Description

S22813TG is highly integrated current mode PWM control IC for flyback convertor. The maximum output power is up to 65W. S22813TG can meet level 6 energy-efficiency standard and EMC requirement easily. The operating voltage of S22813TG is higher than 40V so that is applied to PD and QC charger.

S22813TG has comprehensive protection feature to ensure the reliability of system. The packaging form of S22813TG has SOT23-6.

Features

- Digit frequency shuffling technology to improve EMI performance.
- 器 Fixed 65kHz PWM switching frequency.
- 署 Leading-edge blanking on current sense.
- 署 Internal synchronized slope compensation.
- 光 Low standby power consumption (<75mW@AC 230V)</p>

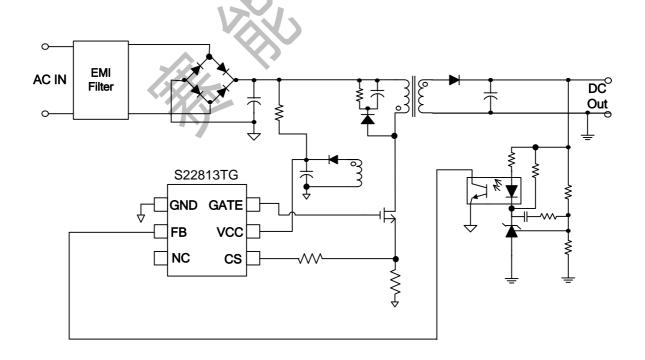
- 署 Soft-start to reduce MOSFET Vds stress during power on
- **♯** Comprehensive protection function
 - 1. Under voltage locked with hysteresis (UVLO) on VDD.
 - 2. Over voltage protection (OVP) on VDD.
 - 3. Cycle-by-Cycle current limitation.
 - 4. Over load protection (OLP)
 - 5. Over temperature protection (OTP)
 - 6. Current limitation compensation to obtain the same output current in universal ac line input
- **X** Low start-up current (<10uA@VDD=12V)
- ₩ 300mA of sinking and 150mA of sourcing current capability in GATE pin

Applications

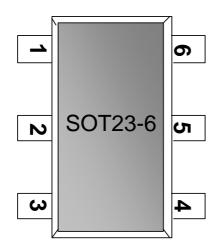
- 署 Cell Phone Charger
- 署 Digital Cameras Charger
- 署 Battery charger

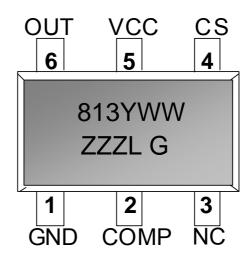
Application Circuit

Two large value resistors are connected to VCC capacitor in startup circuit.



Pin Assignment & Marking Information





813:	22813			
T:	SOT23-6			
Y:	Year code (2022=N,2023=O)			
ww:	week code (01-52)			
ZZZ:	LOT NO			
L:	FAB code			
G:	Wafer code			

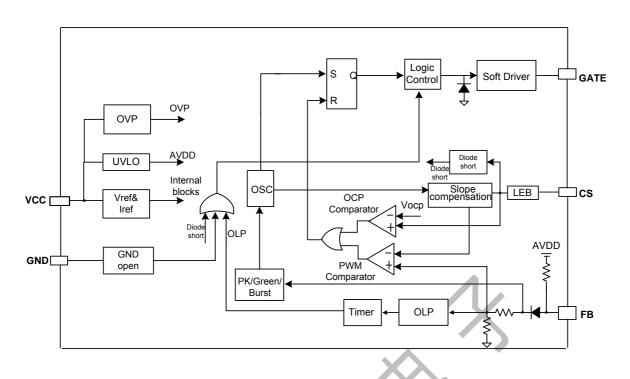
Ordering Information

Part number	Package	MOQ(PCS)
22813TG	SOT23-6	3000

Pin Description

Symbol	Туре	Description		
GATE	0	Totem-pole gate diver output for the power		
VDD	Р	Chip DC power supply pin		
SENSE	I	Current sense input pin.		
FB	I	Feedback input pin.		
Gnd	Р	Ground.		

Block Diagram



Absolute Maximum Rating

Parameter	Value	Unit
VDD clamp voltage	44	V
VDD clamp current	10	mA
VFB input voltage	-0.3 to7	V
VSENSE input voltage to SENSE pin	-0.3 to7	V
Min/Max operating junction temperature	-55 to 150	$^{\circ}\mathbb{C}$
Operating ambient temperature	-20 to 85	$^{\circ}\!\mathbb{C}$
Thermal resistance, Junction to ambient SOT 23-6	250	°C/W

Note: Stresses above absolute maximum ratings may cause permanents damage to the device. Exposure to absolutely maximum-rated conditions for extended periods may affects device reliability

Recommended Operating Conditions

Symbol	Parameter	Min. Max.	Unit
VDD	Supply Voltage Vcc	9 to 40	V
Toa	Operating Ambient temperature	-20 to 85	$^{\circ}$
ESD-HM	Human Model	2	KV
ESD-MM	Machine Model	150	V



Electrical Characteristics ($T_A = 25 \, ^{\circ}\mathrm{C}$, if not otherwise noted)

Complete al	Davamatan	Canditions	Value		Unit		
Symbol	Symbol Parameter Conditions		Min	Тур	Max	Unit	
Supply Voltage (Vdd Pin)							
Idd_start-up	VDD start-up current	VDD=12.5V		3	10	uA	
Idd	VDD Operation current	VDD=16V,FB=3V		1.5		mA	
UVLO(ON)	VDD under voltage lockout enter		6.8	7.8	8.2	V	
UVLO(OFF)	VDD under voltage lockout exit		13	13.4	16.5	V	
VDD_ovp	VDD over voltage protection		41		44	V	
	Voltage Feed	dback (FB Pin)					
AVCS	PWM input gain	VFB/VSENSE		2		V/V	
VFB_open	VFB open loop voltage			5.7		V	
IFB_short	FB pin short current	Short FB pin to GND	90	150	300	uA	
VFB_burst	Burst mode voltage			1.1		V	
VTH_PL	Power limiting FB threshold			3.7		V	
TD_PL	Power limiting delay time			60		mS	
DC_MAX	Maximum duty cycl	VDD=18V, SENSE=0V		75		%	
	Current Sensi	ng (SENSE Pin)					
T_blanking	Leading-edge blanking time		100	400	750	nS	
ZSENSE_IN	Input impedance			40		ΚΩ	
VTH_sense	Over current threshold voltage	Duty=0%	0.62	0.65	0.68	V	
	Osci	llator					
Fosc	Normal oscillation frequency		60	66.5	73	KHz	
Δf_temp	Frequency temperature stability	TA= -20°C to 100°C		5		%	
f_VDD	Frequency voltage stability	VDD=16.5V to 40V		5		%	
Fosc_BM	Burst mode base frequency		17	25	28	KHz	
Δf_OSC	Frequency modulation range Base frequency		-5		+5	%	
Gate Drive Output							
VOL	Output low level	VDD=16V, IO=-20mA			0.8	V	
VOH	Output high level	VDD=16V, IO=20mA	10			V	
V_Clamp	output clamp voltage level			12		V	
T_r	Output rising time	VDD=16V, CL=1nF		1300		nS	
T_f	Output falling time	VDD=16V, CL=1nF		50		nS	



Application Information

22813TG is a highly integrated PWM control IC for the flyback converter. 22813TG is designed specifically for switching power supply that requires level 6 energy-efficiency. The input power is less than 75mW at No-load condition in universal input voltage rang.

Start up Control

22813TG has very low start-up current that is less than 10uA. Therefore, a large resistor can be used in start-up circuit of switch power supply. This will minimize standby dissipation. The typical resistance of start-up resistor is 4M ohms.

Operating Current

The Operating current of 22813TG is less than 1.5mA. Therefore, 22813TG can have good efficiency.

Frequency shuffling for EMI improvement

The frequency Shuffling is implemented in 22813TG. The oscillation frequency is modulated with a random source so that the harmonic energy is spread out. The spread spectrum minimizes the conduction EMI and therefore reduces system design challenge.

Burst Mode Operation

At zero load or light load condition, the main power dissipation in a switching mode power supply is from switching on the MOSFET, the core of transformer and the snubber circuit. The magnitude of power dissipation is proportional to the number of switching frequency within certain period. Less switching frequency can reduce the power dissipation. 22813TG adjusts the switching frequency according to the loading condition. The PWM pulse width is kept greater than 1.2uS at any load condition. From light load to no load, the FB voltage drops. While the FB voltage is less than 1.1V, the gate pin output is disabled and kept low, while the FB voltage is higher than 1.2V, the gate output recovers to normal working mode. This is called 'burst mode'. To reduce audio noise, the switching frequency will be kept higher than 20KHz in burst mode.

Oscillator Operation

The switching frequency is internally fixed at 65kHz. No external frequency setting components are required on PCB design.

Current Sensing and Leading-Edge Blanking

Cycle-by-Cycle current limitation is offered in 22813TG. The switching current is detected by a resistor into the SENSE pin. An internal leading-edge blanking circuit chops off the SENSE voltage spike at initial so that the external RC filtering on SENSE pin is no longer required. The current limiting comparator is disabled and thus cannot turn off the external MOSFET during the blanking period. PWM duty cycle is determined by the voltage in the SENSE pin and the FB pin.

Internal Synchronized Slope Compensation

Slope compensation circuit adds voltage ramp onto the SENSE voltage according to PWM pulse width. This greatly improves the close loop stability at CCM and prevents the sub-harmonic oscillation and thus reduces the output ripple voltage. Slope compensation can help 22813TG obtain the same output current in universal ac input voltage.

Gate Drive

The GATE pin of 22813TG has 300mA of sinking and 150mA of sourcing current capability. Therefore, the MOSFET would be turned on slowly and turned off fast so that 22813TG has high efficiency and low radiation EMI. The highest voltage of drive voltage is clamped at 12V.

Protection Controls

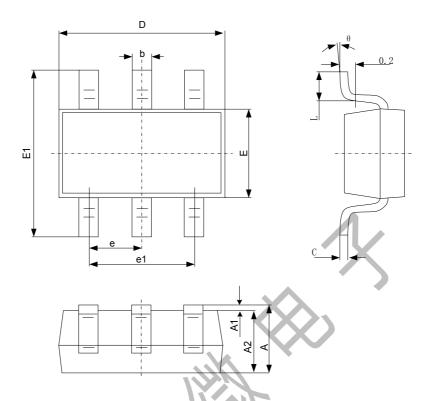
22813TG has comprehensive protection functions, including Cycle-by- Cycle current limitation (OCP), Over Load Protection (OLP) and over voltage clamp, Under Voltage Lockout on VDD (UVLO), Over Temperature Protection (OTP).

Current limitation compensation

To obtain the same output current capability, the OLP threshold voltage is compensated for the different input AC voltage. This function makes the current of OLP is in consistency whatever the AC input is (110V or 220V).

Package Information

SOT-23-6



符号	尺寸 (毫米)		尺寸 (英寸)		
	最小	最大	最小	最大	
Α	0.900	1.200	0.035	0.047	
A1	0.000	0.150	0.000	0.006	
A2	0.900	1.100	0.035	0.043	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.800	3.020	0.110	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.600	3.000	0.102	0.118	
е	0.950	0.950 (中心到中心)		中心到中心)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	